Preliminary Information Low Voltage 1:10 Differential HSTL Clock Fanout Buffer

The Motorola MC100ES8111 is a bipolar monolithic differential clock fanout buffer. Designed for most demanding clock distribution systems, the MC100ES8111 supports various applications that require the distribution of precisely aligned differential clock signals. Using SiGe technology and a fully differential architecture, the device offers very low skew outputs and superior digital signal characteristics. Target applications for this clock driver are high performance clock distribution in computing, networking and telecommunication systems.

Features:

- 1:10 differential clock fanout buffer
- 50 ps maximum device skew¹
- SiGe technology
- Supports DC to 400 MHz operation¹ of clock or data signals
- 1.5V HSTL compatible differential clock outputs
- PECL and HSTL compatible differential clock inputs
- 3.3V power supply for device core, 1.5V or 1.8V HSTL output supply
- Supports industrial temperature range
- Standard 32 lead LQFP package

Functional Description

The MC100ES8111 is designed for low skew clock distribution systems and supports clock frequencies up to 400 MHz¹. The device accepts two clock sources. The CLK0 input accepts HSTL compatible signals and CLK1 accepts PECL compatible signals. The selected input signal is distributed to 10 identical, differential HSTL compatible outputs.

In order to meet the tight skew specification of the device, both outputs of a differential output pair should be terminated, even if only one output is used. In the case where not all 10 outputs are used, the output pairs on the same package side as the parts being used on that side should be terminated.

The HSTL compatible output levels are generated with an open emitter architecture. This minimizes part-to-part and output-to-output skew. The open-emitter outputs require a 50Ω DC termination to GND (0V). The output supply voltage can be either 1.5V or 1.8V, the core voltage supply is 3.3V. The output enable control is synchronized internally preventing output runt pulse generation. Outputs are only disabled or enabled when the outputs are already in logic low state (true outputs logic low, inverted outputs logic high). The internal synchronizer eliminates the setup and hold time requirements for the external clock enable signal. The device is packaged in a 7x7 mm² 32-lead LQFP package.

This document contains information on a product under development. Motorola reserves the right to change or discontinue this product without notice.

1. AC specifications are design targets and subject to change



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Figure 1. MC100ES8111 Logic Diagram

Figure 2. 32–Lead Package Pinout (Top View)

Table 1. PIN CONFIGURATION

Pin	I/O	Туре	Function
CLK0, CLK0	Input	HSTL	Differential HSTL reference clock signal input
CLK1, CLK1	Input	PECL	Differential PECL reference clock signal input
CLK_SEL	Input	LVCMOS	Reference clock input select
OE	Input	LVCMOS	Output enable/disable. OE is synchronous to the input reference clock which eliminates possible output runt pulses when the OE state is changed.
Q[0–9], Q[0–9]	Output	ECL/PECL	Differential clock outputs
GND	Supply		Negative power supply
VCC	Supply		Positive power supply of the device core (3.3V)
VCCO	Supply		Positive power supply of the HSTL outputs. All V_{CCO} pins must be connected to the postive power supply (1.5V or 1.8V) for correct DC and AC operation.

Table 2. FUNCTION TABLE

Control	Default	0	1
CLK_SEL	0	CLK0, CLK0 (HSTL) is the active differential clock input	CLK1, CLK1 (PECL) is the active differential clock input
OE	0	Q[0-9], $\overline{Q[0-9]}$ are active. Deassertion of \overline{OE} can be asynchronous to the reference clock without generation of output runt pulses.	$Q[0-9] = L, \overline{Q[0-9]} = H$ (outputs disabled). Assertion of OE can be asynchronous to the reference clock without generation of output runt pulses.

Table 3. Absolute Maximum Ratings^a

Symbol	Characteristics	Min	Мах	Unit	Condition
VCC	Supply Voltage	-0.3	3.6	V	
Vcco	Supply Voltage	-0.3	3.1	V	
VIN	DC Input Voltage	-0.3	V _{CC} + 0.3	V	
VOUT	DC Output Voltage	-0.3	V _{CC} + 0.3	V	
IIN	DC Input Current		±20	mA	
IOUT	DC Output Current		±50	mA	
ΤS	Storage temperature	-65	125	°C	
T _{Func}	Functional temperature range	T _A = -40	TJ = +110	°C	

a. Absolute maximum continuous ratings are those maximum values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation at absolute-maximum-rated conditions is not implied.

Table 4. General Specifications

Symbol	Characteristics	Min	Тур	Max	Unit	Condition
VTT	Output termination voltage		0		V	
MM	ESD Protection (Machine model)	200			V	
HBM	ESD Protection (Human body model)	2000			V	
CDM	ESD Protection (Charged device model)	TBD			V	
LU	Latch-up immunity	200			mA	
CIN	Input Capacitance		4.0		pF	Inputs
ΑL ^θ	Thermal resistance junction to ambient JESD 51-3, single layer test board JESD 51-6, 2S2P multilayer test board		83.1 73.3 68.9 63.8 57.4 59.0 54.4 52.5 50.4 47.8	86.0 75.4 70.9 65.3 59.6 60.6 55.7 53.8 51.5 48.8	°C/W °C/W °C/W °C/W °C/W °C/W °C/W °C/W	Natural convection 100 ft/min 200 ft/min 400 ft/min 800 ft/min Natural convection 100 ft/min 200 ft/min 400 ft/min 800 ft/min
θJC	Thermal resistance junction to case		23.0	26.3	°C/W	MIL-SPEC 883E Method 1012.1
ТJ	Operating junction temperature ^a (continuous operation) MTBF = 9.1 years			110	°C	

a. Operating junction temperature impacts device life time. Maximum continues operating junction temperature should be selected according to the application life time requirements (See application note AN1545 and the application section in this datasheet for more information). The device AC and DC parameters are specified up to 110°C junction temperature allowing the MC100ES8111 to be used in applications requiring industrial temperature range. It is recommended that users of the MC100ES8111 employ thermal modeling analysis to assist in applying the junction temperature specifications to their particular application.

Symbol	Characteristics	Min	Тур	Max	Unit	Condition
Clock inp	ut pair CLK0, CLK0 (HSTL differential signals)		•		
VDIF	Differential input voltage ^b	0.2			V	
VX, IN	Differential cross point voltage ^C	0.25	0.68 - 0.9	V _{CC} -1.3	V	
ViH	Input high voltage	V _X +0.1			V	
VIL	Input low voltage			V _X -0.1	V	
IIN	Input Current			±150	mA	$V_{IN} = V_X \pm 0.1V$
Clock inp	ut pair CLK1, CLK1 (PECL differential signals	5)				
VPP	Differential input voltaged	0.15		1.0	V	Differential operation
VCMR	Differential cross point voltage ^e	1.0		VCC-0.6	V	Differential operation
VIH	Input voltage high	V _{CC} -1.165		V _{CC} -0.880	V	
VIL	Input voltage low	V _{CC} -1.810		V _{CC} -1.475	V	
IIN	Input Current ^a			±150	mA	$V_{IN} = V_{IH} \text{ or } V_{IN}$
LVCMOS	control inputs OE, CLK_SEL	•				
VIL	Input voltage low			0.8	V	
VIH	Input voltage high	2.0			V	
IIN	Input Current			±150	mA	$V_{IN} = V_{IH} \text{ or } V_{IN}$
HSTL clo	ck outputs (Q[0-9], Q[0-9])	•				
Vx,out	Output differential crosspoint	0.68	0.75	0.9	V	
VOH	Output High Voltage	1			V	
VOL	Output Low Voltage			0.4	V	
Supply cu	urrent			•		
ICC	Maximum Quiescent Supply Current without output termination current		100	TBD	mA	V _{CC} pin (core)
ICCOf	Maximum Quiescent Supply Current, outputs terminated 50Ω to VTT		TBD	TBD	mA	V _{CCO} pins (outputs)

Table 5. DC Characteristics (V $\circ \circ$ = 3.3V±5%.	V _{CCO} =1.5V±0.1V or V _{CCO} =1.8V±0.1V, T _J = 0°C to + 110°C) ^a

a. DC characteristics are design targets and pending characterization.

b. V_{DIF} (DC) is the minimum differential HSTL input voltage swing required for device functionality.
c. V_X (DC) is the crosspoint of the differential HSTL input signal. Functional operation is obtained when the crosspoint is within the V_X (DC) range and the input swing lies within the V_{PP} (DC) specification.

d. Vpp (DC) is the minimum differential input voltage swing required to maintain device functionality.

e. V_{CMR} (DC) is the crosspoint of the differential input voltage owing required to maintain device functionality.
 e. V_{CMR} (DC) is the crosspoint of the differential input signal. Functional operation is obtained when the crosspoint is within the V_{CMR} (DC) range and the input swing lies within the V_{PP} (DC) specification.
 f. I_{CC} includes current through the output resistors (all outputs terminated to V_{TT}).

Symbol	Characteristics	Min	Тур	Max	Unit	Condition
Clock inp	ut pair CLK0, CLK0 (HSTL differential signals)					
VDIF	Differential input voltage ^C (peak-to-peak)	0.4			V	
VX, IN	Differential cross point voltaged	0.68		0.9	V	
^f CLK	Input Frequency		0-400	TBD	MHz	
^t PD	Propagation Delay CLK0 to Q[0-9]			TBD	ps	
Clock inp	ut pair CLK1, CLK1 (PECL differential signals)					-
Vpp	Differential input voltage ^e (peak-to-peak)	0.2		1.0	V	
VCMR	Differential input crosspoint voltage ^f	1		V _{CC} -0.6	V	
^f CLK	Input Frequency		0-400		MHz	Differential
tPD Propagation Delay CLK1 to Q[0-9]				TBD	ps	Differential
HSTL clo	ck outputs (Q[0-9], Q[0-9])					
Vx,out	Output differential crosspoint	0.68	0.75	0.9	V	
VOH	Output High Voltage	1			V	
VOL	Output Low Voltage			0.5	V	
VO(P-P)	Differential output voltage (peak-to-peak)	0.5			V	
^t sk(O)	Output-to-output skew			50	ps	Differential
^t sk(PP)	Output-to-output skew (part-to-part)			TBD	ps	Differential
^t JIT(CC)	Output cycle-to-cycle jitter			TBD		
DCO	Output duty cycle	TBD	50	TBD	%	DC _{fref} = 50%
t _r , t _f	Output Rise/Fall Time	0.05		TBD	ns	20% to 80%
t _{PDL} g	Output disable time	2.5·T + tpD		3.5·T + tpD	ns	T=CLK period
^t PLD ^h	Output enable time	3·T + tpD		4·T + t _{PD}	ns	T=CLK period

Table 6. AC Characteristics (V_{CC} = 3.3V±5%, V_{CCO} = 1.5V±0.1V or V_{CCO} = 1.8V±0.1V, T_J = 0°C to + 110°C) a b

a. AC characteristics are design targets and pending characterization.

b. AC characteristics apply for parallel output termination of 50Ω to V_{TT}.

c. VDIF (DC) is the minimum differential HSTL input voltage swing required for device functionality.

d. V_{χ} (DC) is the crosspoint of the differential HSTL input signal. Functional operation is obtained when the crosspoint is within the V_{χ} (DC) range and the input swing lies within the V_{DIF} (DC) specification.

e. Vpp (AC) is the minimum differential PECL input voltage swing required to maintain AC characteristics including tpd and device-to-device skew.

f. V_{CMR} (AC) is the crosspoint of the differential HSTL input signal. Normal AC operation is obtained when the crosspoint is within the V_{CMR} (AC) range and the input swing lies within the V_{PP} (AC) specification. Violation of V_{CMR} (AC) or V_{PP} (AC) impacts the device propagation delay, device and <u>part</u>-to-part skew.

g. Propagation delay OE deassertion to differential output disabled (differential low: true output low, complementary output high).

h. Propagation delay OE assertion to output enabled (active).



Figure 1. MC100ES8111 AC test reference



Figure 2. MC100ES8111 AC test reference







Figure 4. MC100ES8111 AC reference measurement waveform (PECL input)

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